











TPS61194-Q1

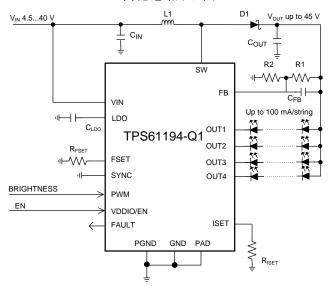
ZHCSEO9D - JANUARY 2016-REVISED MAY 2017

TPS61194-Q1 具有四条 100mA 通道的低 EMI 汽车 LED 驱动器

1 特性

- 符合汽车应用要求
- 具有符合 AEC-Q100 标准的下列结果:
 - 器件温度 1 级: -40℃ 至 +125℃ 的环境运行温度范围
- 输入工作电压范围: 4.5V 至 40V
- 四路高精度电流阱
 - 电流匹配率为 1% (典型值)
 - 发光二极管 (LED) 灯串电流高达 100mA/通道
 - 输出可在外部合并,从而提高每条灯串的电流
- 100Hz 频率下的调光比率高达 10000:1
- 适用于 LED 灯串电源的集成升压/SEPIC 转换器
 - 输出电压高达 45V
 - 开关频率: 300kHz 至 2.2MHz
 - 开关同步输入
 - 扩展频谱,用于降低电磁干扰 (EMI)
- 丰富的故障检测功能 特性
 - 故障输出
 - 输入过压保护 (OVP) 和欠压锁定 (UVLO)
 - 开路和短路 LED 故障检测
 - 热关断
- 最大限度减少外部组件数

简化电路原理图



Copyright © 2016. Texas Instruments Incorporated

2 应用

- 为以下应用提供背光:
 - 汽车信息娱乐系统
 - 汽车仪表盘
 - 智能车镜
 - 抬头显示屏 (HUD)
 - 中央信息显示屏 (CID)
 - 音视频导航 (AVN)

3 说明

TPS61194-Q1 是一款集成 DC-DC 转换器的低电磁干扰 (EMI) 且易于使用的汽车类高效 LED 驱动器。DC-DC 转换器支持升压和 SEPIC 工作模式。该器件具备的四路高精度电流阱可进行组合,以提高电流能力。

DC-DC 转换器可基于 LED 电流阱余量电压提供自适应输出电压控制。该特性可在所有条件下将电压调节到能够满足需要的最低水平,从而最大限度降低功耗。为了降低 EMI,DC-DC 转换器支持针对开关频率进行扩频以及使用专用引脚实现外部同步。凭借较大的可调节频率范围,TPS61194-Q1 能够避免调幅无线电频带干扰。

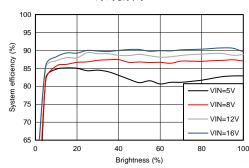
TPS61194-Q1 的输入电压范围为 4.5V 至 40V,支持汽车启动/停止以及负载突降情况。TPS61194-Q1 集成了丰富的故障检测 功能的反馈。

器件信息(1)

	HITTH'C						
器件型号	封装	封装尺寸 (标称值)					
TPS61194-Q1	HTSSOP (20)	6.50mm x 4.40mm					

(1) 要了解所有可用封装,请参见数据表末尾的可订购产品附录。

系统效率



1

2



特性	1	8.1 Overview	11
应用	1	8.2 Functional Block Diagram	12
说明	1	8.3 Feature Description	13
修订历史记录		8.4 Device Functional Modes	19
器件比较表		9 Application and Implementation	21
Pin Configuration and Functions		9.1 Application Information	21
Specifications		9.2 Typical Applications	21
7.1 Absolute Maximum Ratings		10 Power Supply Recommendations	26
7.1 Absolute Maximum Ratings		11 Layout	27
7.2 ESD Ratings		11.1 Layout Guidelines	27
7.4 Thermal Information		11.2 Layout Example	
7.5 Flectrical Characteristics		12 器件和文档支持	29

目录

4 修订历史记录

注: 之前版本的页码可能与当前版本有所不同。

7.7 Protection Electrical Characteristics 6

7.9 PWM Brightness Control Electrical Characteristics.. 7

7.10 Boost and SEPIC Converter Characteristics 7

Detailed Description 11

Cł	nanges from Revision C (April 2017) to Revision D	Page
•	Enhanced pin descriptions for pins 3, 10 and 16 in <i>Pin Functions</i>	4
•	Deleted "Dimming ratio is calculated as ratio between the input PWM period and minimum on/off time (0.5 µs). " from <i>Brightness Control</i>	15
Cł	nanges from Revision B (October 2016) to Revision C	Page
•	Deleted "I _{OUT} = 100 mA" from t _{ON/OFF} row of Table 7.9	7
•	Changed "0.5" from MAX to TYP column in t _{ON/OFF} row of Table 7.9	<mark>7</mark>
•	Added table note 1 for Tables 7.9 and 7.10	<mark>7</mark>
•	Deleted "Initial DC-DC voltage is about 88% of V _{MAX BOOST} ." from <i>Integrated DC-DC Converter</i> , change wording in last sentence before equation 1.	13
•	Changed eq. 1; added "K" eq definitions for eq. 1 and paragraph after Fig. 9	13
•	Added new paragraph before Internal LDO	
Cł	nanges from Revision A (January 2016) to Revision B	Page
_		
•	已删除 特性中多个条目的 <i>措辞</i> 已更改 "输出电流"至"LED 灯串电流"以及"200Hz 频率下的调光比率高达 10000:1"至"100Hz 频率下的调光比率高达 10000:1"	
•	已添加 其他 <i>应用</i>	
	已更改 说明中的多处 <i>措辞</i> - 为了清晰起见	
	己更改"高开关频率"更改为"宽范围可调频率"	
	已添加 器件比较表	
	Added 2 new LED Current graphs	



Changes from Original (December 2015) to Revision A

Page

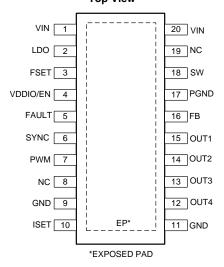
5 器件比较表

	LP8860-Q1	LP8862-Q1	LP8861-Q1	TPS61193-Q1	TPS61194-Q1	TPS61196-Q1
VIN 范围	3V 至 48V	4.5V 至 40V	4.5V 至 45V	4.5V 至 40V	4.5V 至 40V	8V 至 30V
LED 通道的数量	4	2	4	3	4	6
LED 电流/通道	150mA	160mA	100mA	100mA	100mA	200mA
I2C/SPI 支持	有	無	無	無	無	無
SEPIC 支持	否	有	是	是	是	无



6 Pin Configuration and Functions

PWP Package 20-Pin HTSSOP With Exposed Thermal Pad Top View



Pin Functions

	PIN	->(1)	
NO.	NAME	TYPE ⁽¹⁾	DESCRIPTION
1	VIN	Α	Input power pin
2	LDO	Α	Output of internal LDO; connect a 1-μF decoupling capacitor between this pin and noise-free GND.
3	FSET	Α	DC-DC (boost or SEPIC) switching frequency setting resistor; for normal operation, resistor value from 24 k Ω to 219 k Ω must be connected between this pin and ground.
4	VDDIO/EN	Ι	Enable input for the device as well as supply input (VDDIO) for digital pins
5	FAULT	OD	Fault signal output. If unused, the pin may be left floating.
6	SYNC	Ι	Input for synchronizing boost. If synchronization is not used, connect this pin to GND to disable spread spectrum or to VDDIO/EN to enable spread spectrum.
7	PWM		PWM dimming input.
8	NC	l	No connect
9	GND	G	Ground.
10	ISET	Α	LED current setting resistor; for normal operation, resistor value from 24 k Ω to 129 k Ω must be connected between this pin and ground.
11	GND	G	Ground
12	OUT4	Α	Current sink output This pin must be connected to GND if not used.
13	OUT3	Α	Current sink output This pin must be connected to GND if not used.
14	OUT2	Α	Current sink output This pin must be connected to GND if not used.
15	OUT1	Α	Current sink output This pin must be connected to GND if not used.
16	FB	А	DC-DC (boost or SEPIC) feedback input; for normal operation this pin must be connected to the middle of a resistor divider between V_{OUT} and ground using feedback resistor values from 5 k Ω to 150 k Ω .
17	PGND	G	DC-DC (boost or SEPIC) power ground
18	SW	Α	DC-DC (boost or SEPIC) switch pin
19	NC	Α	No connect
20	VIN	Α	Input power pin

(1) A: Analog pin, G: Ground pin, P: Power pin, I: Input pin, I/O: Input/Output pin, O: Output pin, OD: Open Drain pin



Specifications

7.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted)(1)(2)

		MIN	MAX	UNIT
	VIN, SW, FB	-0.3	50	
Voltage on pins	OUT1, OUT2, OUT3, OUT4	-0.3	45	V
	LDO, SYNC, FSET, ISET, PWM, VDDIO/EN, FAULT	-0.3	5.5	
Continuous power	dissipation ⁽³⁾	Internally	Limited	
Ambient temperatu	ure range T _A ⁽⁴⁾	-40	,	
Junction temperate	ure range T _J ⁽⁴⁾	-40	150	°C
Maximum lead ten	nperature (soldering)		See ⁽⁵⁾	
Storage temperatu	ire, T _{stg}	-65	150	°C

Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltages are with respect to the potential at the GND pins.

7.2 ESD Ratings

				VALUE	UNIT
		Human-body model (HBM), per AEC Q100-002 ⁽¹⁾		±2000	
$V_{(ESD)}$	Electrostatic discharge	Charged-device model (CDM), per AEC Q100-	All other pins	±500	V
		011	Corner pins (1,10,11,20)	±750	

⁽¹⁾ AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

7.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
	VIN	4.5	45	
	SW	0	45	
Voltage on pins	OUT1, OUT2, OUT3, OUT4	0	40	V
	FB, FSET, LDO, ISET, VDDIO/EN, FAULT	0	5.25	
	SYNC, PWM	0	VDDIO/EN	

(1) All voltages are with respect to the potential at the GND pins.

Internal thermal shutdown circuitry protects the device from permanent damage. Thermal shutdown engages at T_J = 165°C (typical) and disengages at T_J = 145°C (typical).

In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature may have to be derated. Maximum ambient temperature (T_{A-MAX}) is dependent on the maximum operating junction temperature (T_{J-MAX-OP} = 150°C), the maximum power dissipation of the device in the application (P_{D-MAX}), and the junction-to ambient thermal resistance of the part/package in the application ($R_{\theta JA}$), as given by the following equation: $T_{A-MAX} = T_{J-MAX-OP} - (R_{\theta JA} \times P_{D-MAX})$. For detailed soldering specifications and information, refer to the *PowerPADTM Thermally Enhanced Package*.



7.4 Thermal Information

		TPS61194-Q1	
	THERMAL METRIC ⁽¹⁾	PWP (HTSSOP)	UNIT
		20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance (2)	44.2	°C/W
$R_{\theta JCtop}$	Junction-to-case (top) thermal resistance	26.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	22.4	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.9	°C/W
ΨЈВ	Junction-to-board characterization parameter	22.2	°C/W
$R_{\theta JCbot}$	Junction-to-case (bottom) thermal resistance	2.5	°C/W

(1) For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics.

7.5 Electrical Characteristics (1)(2)

 $T_1 = -40$ °C to +125°C (unless otherwise noted).

· ·	•	,				
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Standby supply current	Device disabled, $V_{VDDIO/EN} = 0 V$, $V_{IN} = 12 V$		4.5	20	μΑ
l _Q	Active supply current	$V_{\rm IN}$ = 12 V, $V_{\rm OUT}$ = 26 V, output current 80 mA/channel, converter $f_{\rm SW}$ = 300 kHz		5	12	mA
V _{POR_R}	Power-on reset rising threshold	LDO pin voltage			2.7	V
V_{POR_F}	Power-on reset falling threshold	LDO pin voltage	1.5			V
T _{TSD}	Thermal shutdown threshold		150	165	175	°C
T _{TSD_HYST}	Thermal shutdown hysteresis			20		°C

7.6 Internal LDO Electrical Characteristics

 $T_J = -40$ °C to +125°C (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{LDO}	Output voltage	V _{IN} = 12 V	4.15	4.3	4.55	V
V_{DR}	Dropout voltage		120	300	430	mV
I _{SHORT}	Short circuit current			50		mA

7.7 Protection Electrical Characteristics

 $T_J = -40$ °C to +125°C (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OVP}	VIN OVP threshold voltage		41	42	44	V
V_{UVLO}	VIN UVLO			4		V
V _{UVLO_HYST}	VIN UVLO hysteresis			100		mV
	LED short detection threshold		5.6	6	7	V

Junction-to-ambient thermal resistance is highly application and board-layout dependent. In applications where high maximum power dissipation exists, special care must be paid to thermal dissipation issues in board design.

⁽¹⁾ All voltages are with respect to the potential at the GND pins.(2) Minimum and maximum limits are specified by design, test, or statistical analysis.



7.8 Current Sinks Electrical Characteristics

 $T_J = -40$ °C to +125°C (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I _{LEAKAGE}	Leakage current	Outputs OUT1 to OUT4 , $V_{OUTx} = 45 \text{ V}$		0.1	5	μΑ
I _{MAX}	Maximum current	OUT1, OUT2, OUT3, OUT4		100		mA
I _{OUT}	Output current accuracy	I _{OUT} = 100 mA	-5%		5%	
I _{MATCH}	Output current matching ⁽¹⁾	I _{OUT} = 100 mA, PWM duty =100%		1%	5%	
V _{SAT}	Saturation voltage (2)	I _{OUT} = 100 mA		0.4	0.7	V

⁽¹⁾ Output Current Accuracy is the difference between the actual value of the output current and programmed value of this current. Matching is the maximum difference from the average. For the constant current sinks on the part (OUTx), the following are determined: the maximum output current (MAX), the minimum output current (MIN), and the average output current of all outputs (AVG). Matching number is calculated: (MAX-MIN)/AVG. The typical specification provided is the most likely norm of the matching figure for all parts. LED current sinks were characterized with 1-V headroom voltage. Note that some manufacturers have different definitions in use.

7.9 PWM Brightness Control Electrical Characteristics

 $T_J = -40$ °C to +125°C (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f_{PWM}	PWM input frequency		100		20 000	Hz
t _{ON/OFF}	Minimum on/off time ⁽¹⁾			0.5		μs

⁽¹⁾ This specification is not ensured by ATE.

7.10 Boost and SEPIC Converter Characteristics

 $T_J = -40$ °C to +125°C (unless otherwise noted).

Unless otherwise specified: $V_{IN} = 12 \text{ V}$, $V_{EN/VDDIO} = 3.3 \text{ V}$, $L = 22 \mu\text{H}$, $C_{IN} = 2 \times 10 - \mu\text{F}$ ceramic and 33- μF electrolytic, D = NRVB460MFS, $f_{SW} = 300 \text{ kHz}$.

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{IN}	Input voltage		4.5		40	V
V _{OUT}	Output voltage		6		45	
f_{SW_MIN}	Minimum switching frequency (central frequency if spread spectrum is enabled)	Defined by D		300		kHz
fsw_max	Maximum switching frequency (central frequency if spread spectrum is enabled)	Defined by R _{FSET} resistor		2 200		kHz
V _{OUT} /V _{IN}	Conversion ratio				10	
T _{OFF}	Minimum switch OFF time ⁽¹⁾	f _{SW} ≥ 1.15 MHz			55	ns
I _{SW_MAX}	SW current limit		1.8	2	2.2	Α
R _{DSON}	FET R _{DSON}	Pin-to-pin		240	400	mΩ
f _{SYNC}	External SYNC frequency		300		2 200	kHz
t _{SYNC_ON_MIN}	External SYNC minimum on time (1)			150		ns
tsync_off_min	External SYNC minimum off time (1)			150		ns

⁽¹⁾ This specification is not ensured by ATE.

7.11 Logic Interface Characteristics

 $T_J = -40$ °C to +125°C (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT				
LOGIC INPUT VDDIO/EN										
V _{IL}	Input low level				0.4	\/				
V_{IH}	Input high level		1.65			V				
I	Input current		-1	5	30	μΑ				
LOGIC INPUT SYNC/FSET, PWM										

⁽²⁾ Saturation voltage is defined as the voltage when the LED current has dropped 10% from the value measured at 1 V.



Logic Interface Characteristics (continued)

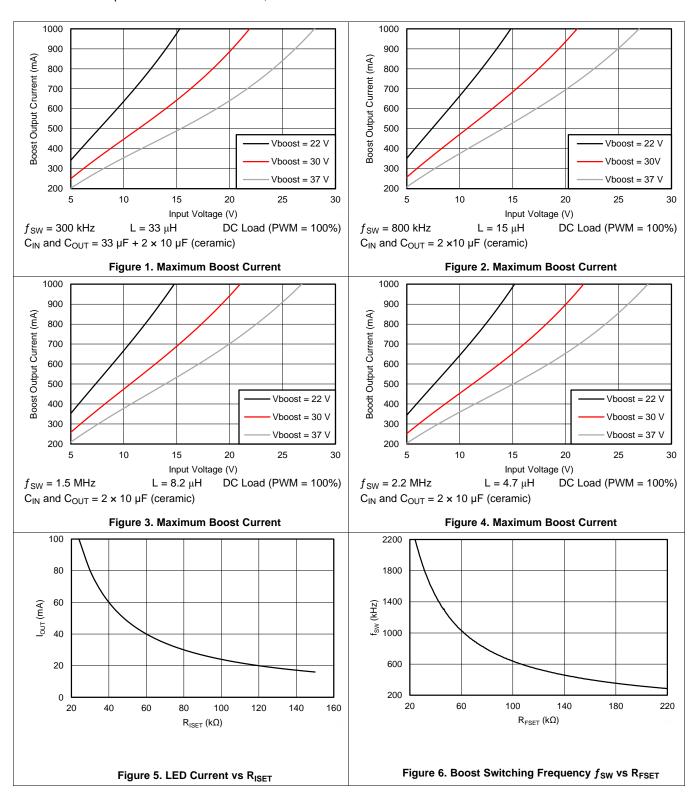
 $T_J = -40$ °C to +125°C (unless otherwise noted).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT				
V_{IL}	Input low level			0.2 ×	VDDIO/EN	V				
V_{IH}	Input high level		0.8 × VDDIO/EN			V				
II	Input current		-1		1	μΑ				
LOGIC OUTPUT FAULT										
V _{OL}	Output low level	Pullup current 3 mA		0.3	0.5	V				
I _{LEAKAGE}	Output leakage current	V = 5.5 V			1	μΑ				



7.12 Typical Characteristics

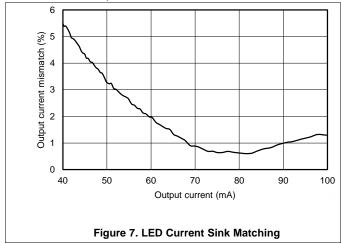
Unless otherwise specified: D = NRVB460MFS, T = 25°C

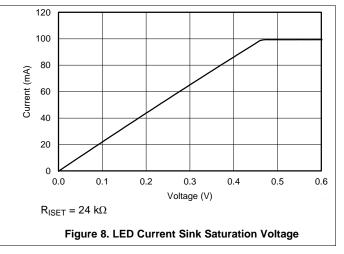




Typical Characteristics (continued)

Unless otherwise specified: D = NRVB460MFS, T = 25°C







8 Detailed Description

8.1 Overview

The TPS61194-Q1 is a highly integrated LED driver for automotive infotainment, lighting system and medium-sized LCD backlight applications. It includes a DC-DC with an integrated FET, supporting both boost and SEPIC modes, an internal LDO enabling direct connection to battery without need for a pre-regulated supply and four LED current sinks. The VDDIO/EN pin provides the supply voltage for digital IOs (PWM and SYNC inputs) and at the same time enables the device.

The switching frequency on the DC-DC converter is set by a resistor connected to the FSET pin. The maximum voltage of the DC-DC is set by a resistive divider connected to the FB pin. For the best efficiency the output voltage is adapted automatically to the minimum necessary level needed to drive the LED strings. This is done by monitoring LED output voltage drop in real time. For EMI reduction and control two optional features are available:

- · Spread spectrum, which reduces EMI noise around the switching frequency and its harmonic frequencies
- DC-DC can be synchronized to an external frequency connected to SYNC pin

The four constant current outputs OUT1, OUT2, OUT3, and OUT4 provide LED current up to 100 mA.Value for the current per OUT pin is set with a resistor connected to ISET pin. Current sinks that are not used must be connected to ground. Grounded current sink is disabled and excluded from adaptive voltage detection loop.

Brightness is controlled with the PWM input. Frequency range for the input PWM is from 100 Hz to 20 kHz. LED output PWM follows the input PWM so the output frequency is equal to the input frequency.

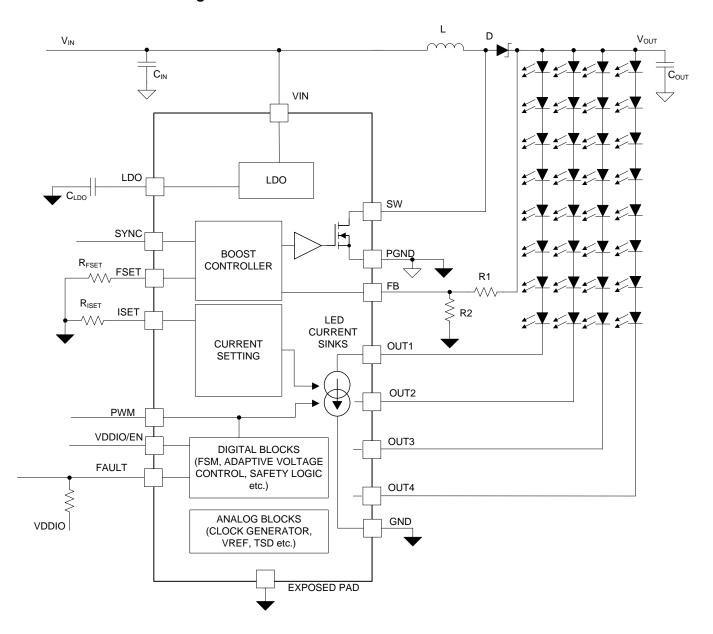
TPS61194-Q1 has extensive fault detection features :

- · Open-string and shorted LED detections
 - LED fault detection prevents system overheating in case of open or short in some of the LED strings
- V_{IN} input overvoltage protection
 - Threshold sensing from VIN pin
- V_{IN} input undervoltage protection
 - Threshold sensing from VIN pin
- Thermal shutdown in case of die overtemperature

Fault condition is indicated through the FAULT output pin.



8.2 Functional Block Diagram



(1)



8.3 Feature Description

8.3.1 Integrated DC-DC Converter

The TPS61194-Q1 DC-DC converter generates supply voltage for the LEDs and can operate in boost mode or in SEPIC mode. The maximum output voltage $V_{OUT\ MAX}$ is defined by an external resistive divider (R1, R2).

V_{OUT_MAX} voltage should be chosen based on the maximum voltage required for LED strings. Recommended maximum voltage is about 30% higher than maximum LED string voltage. DC-DC output voltage is adjusted automatically based on LED current sink headroom voltage. Maximum, minimum, and initial boost voltages can be calculated with Equation 1:

$$V_{BOOST} = \left(\frac{V_{BG}}{R2} + K \times 0.0387\right) \times R1 + V_{BG}$$

where

- V_{BG} = 1.2 V
- R2 recommended value is 130 kΩ
- Resistor values are in kΩ
- K = 1 for maximum adaptive boost voltage (typical)
- K = 0 for minimum adaptive boost voltage (typical)
- K = 0.88 for initial boost voltage (typical)

45 (2) 96 and 30 (3) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40 (2) 40

Figure 9. Maximum Converter Output Voltage vs R1 Resistance

R1 (kΩ)

Alternatively, a T-divider can be used if resistance less than 100 k Ω is required for the external resistive divider. Refer to *Using the TPS61194xEVM Evaluation Module* for details.

The converter is a current mode DC-DC converter, where the inductor current is measured and controlled with the feedback. Switching frequency is adjustable between 250 kHz and 2.2 MHz with R_{FSET} resistor as Equation 2:

$$f_{SW} = 67600 / (R_{FSET} + 6.4)$$

10

where

- f_{SW} is switching frequency, kHz
- R_{ESET} is frequency setting resistor, $k\Omega$

300

In most cases lower frequency has higher system efficiency. DC-DC internal parameters are chosen automatically according to the selected switching frequency (see Table 2) to ensure stability. In boost mode a 15-pF capacitor C_{FB} must be placed across resistor R1 when operating in 300-kHz to 500-kHz range (see *Typical Application for 4 LED Strings*). When operating in the 1.8-MHz to 2.2-MHz range C_{FB} = 4.7 pF.

(2)



Feature Description (continued)

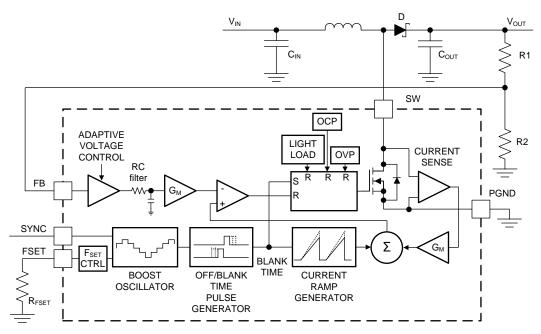


Figure 10. Boost Block Diagram

DC-DC can be driven by an external SYNC signal between 300 kHz and 2.2 MHz. If the external synchronization input disappears, DC-DC continues operation at the frequency defined by R_{FSET} resistor. When external frequency disappears and SYNC pin level is low, converter continues operation without spread spectrum immediately. If SYNC remains high, converter continues switching with spread spectrum enabled after 256 µs.

External SYNC frequency must be 1.2 to 1.5 times higher than the frequency defined by R_{FSET} resistor. Minimum frequency setting with R_{FSET} is 250 kHz to support 300-kHz switching with external clock.

The optional spread spectrum feature (±3% from central frequency, 1-kHz modulation frequency) reduces EMI noise at the switching frequency and its harmonic frequencies. When external synchronization is used, spread spectrum is not available.

Table 1. DC-DC Synchronization Mode

SYNC PIN INPUT	MODE
Low	Spread spectrum disabled
High	Spread spectrum enabled
300 to 2200 kHz frequency	Spread spectrum disabled, external synchronization mode

Table 2. DC-DC Parameters (1)

RANGE	FREQUENCY (kHz)	TYPICAL INDUCTANCE (µH)	AND OUTPUT		CURRENT RAMP (A/s)	CURRENT RAMP DELAY (ns)	
1	300 to 480	33	2 x10 (cer.) + 33 (electr.)	150	95	24	550
2	480 to 1150	15	10 (cer.) + 33 (electr.)	60	95	43	300
3	1150 to 1650	10	3 x 10 (cer.)	40	95	79	0
4	1650 to 2200	4.7	3 x 10 (cer.)	40	70	145	0

(1) Parameters are for reference only

(2) Due to current sensing comparator delay the actual minimum off time is 6 ns (typical) longer than in the table.



The converter SW pin DC current is limited to 2 A (typical). To support warm-start transient condition the current limit is automatically increased to 2.5 A for a short period of 1.5 seconds when a 2-A limit is reached.

NOTE

Application condition where the 2-A limit is exceeded continuously is not allowed. In this case the current limit would be 2 A for 1.5 seconds followed by 2.5-A limit for 1.5 seconds, and this 3-second period repeats.

To keep switching voltage within safe levels there is a 48-V limit comparator in the event that FB loop is broken.

8.3.2 Internal LDO

The internal LDO regulator converts the input voltage at VIN to a 4.3-V output voltage for internal use. Connect a minimum of 1-µF ceramic capacitor from LDO pin to ground, as close to the LDO pin as possible.

8.3.3 LED Current Sinks

8.3.3.1 Output Configuration

TPS61194-Q1 detects LED output configuration during start-up. Any current sink output connected to ground is disabled and excluded from the adaptive voltage control of the DC-DC and fault detections.

8.3.3.2 Current Setting

Maximum current for the LED outputs is controlled with external R_{ISET} resistor. R_{ISET} value for target maximum current can be calculated using Equation 3:

$$R_{ISET} = 2342 / (I_{OUT} - 2.5)$$

where

- R_{ISET} is current setting resistor, kΩ
- I_{LED} is output current per output, mA

8.3.3.3 Brightness Control

TPS61194-Q1 controls the brightness of the display with conventional PWM. Output PWM directly follows the input PWM. Input PWM frequency can be in the range of 100 Hz to 20 kHz.

8.3.4 Protection and Fault Detections

The TPS61194-Q1 has fault detection for LED open and short, VIN input overvoltage protection (VIN_OVP), VIN undervoltage lockout (VIN_UVLO), and thermal shutdown (TSD).

8.3.4.1 Adaptive DC-DC Voltage Control and Functionality of LED Fault Comparators

Adaptive voltage control function adjusts the DC-DC output voltage to the minimum sufficient voltage for proper LED current sink operation. The current sink with highest V_F LED string is detected and DC-DC output voltage adjusted accordingly. DC-DC adaptive control voltage step size is defined by maximum voltage setting, $V_{STEP} = (V_{OUT_MAX} - V_{OUT_MIN}) / 256$. Periodic down pressure is applied to the target voltage to achieve better system efficiency.

Every LED current sink has 3 comparators for the adaptive DC-DC control and LED fault detections. Comparator outputs are filtered, filtering time is 1 µs.

(3)

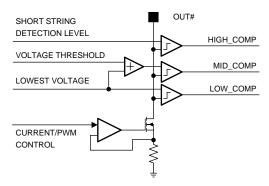


Figure 11. Comparators for Adaptive Voltage Control and LED Fault Detection

Figure 12 shows different cases which cause DC-DC voltage increase, decrease, or generate faults. In normal operation voltage at all the OUT# pins is between LOW_COMP and MID_COMP levels, and boost voltage stays constant. LOW_COMP level is the minimum for proper LED current sink operation, 1.1 × V_{SAT} + 0.2 V (typical). MID_COMP level is 1.1 × V_{SAT} + 1.2 V (typical) so typical headroom window is 1 V.

When voltage at all the OUT# pins increases above MID_COMP level, DC-DC voltage adapts downwards.

When voltage at any of the OUT# pins falls below LOW_COMP threshold, DC-DC voltage adapts upwards. In the condition where DC-DC voltage reaches the maximum and there are one or more outputs still below LOW_COMP level, an open LED fault is detected.

HIGH_COMP level, 6 V typical, is the threshold for shorted LED detection. When the voltage of one or more of the OUT# pins increases above HIGH_COMP level and at least one of the other outputs is within the normal headroom window, shorted LED fault is detected.

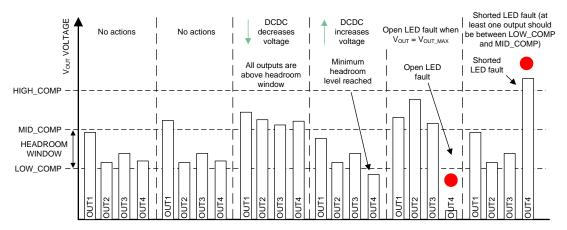


Figure 12. Protection and DC-DC Voltage Adaptation Algorithms



8.3.4.2 Overview of the Fault/Protection Schemes

A summary of the TPS61194-Q1fault detection behavior is shown in Table 3. Detected faults (excluding LED open or short) cause device to enter FAULT_RECOVERY state. In FAULT_RECOVERY the DC-DC and LED current sinks of the device are disabled, and the FAULT pin is pulled low. The device recovers automatically and enters normal operating mode (ACTIVE) after a recovery time of 100 ms if the fault condition has disappeared. When recovery is successful, FAULT pin is released.

If a LED fault is detected, the device continues normal operation and only the faulty string is disabled. The fault is indicated via the FAULT pin which can be released by toggling VDDIO/EN pin low for a short period of 2 µs to 20 µs. LEDs are turned off for this period but the device stays in ACTIVE mode. If VDDIO/EN is low longer, the device goes to STANDBY and restarts when EN goes high again.

Table 3. Fault Detections

FAULT/ PROTECTION	FAULT NAME	THRESHOLD	FAULT PIN	FAULT_ RECOVERY STATE	ACTION
VIN overvoltage protection	VIN_OVP	1. V _{IN} > 42 V 2. V _{OUT} > V _{SET_DCDC} + 610 V. V _{SET_DCDC} is voltage value defined by logic during adaptation	Yes	Yes	1. Overvoltage is monitored from the beginning of soft start. Fault is detected if the duration of overvoltage condition is 100 μs minimum. 2. Overvoltage is monitored from the beginning of normal operation (ACTIVE mode). Fault is detected if over-voltage condition duration is 560 ms minimum (t_{filter}). After the first fault, detection filter time is reduced to 50 ms for following recovery cycles. When the device recovers and has been in ACTIVE mode for 160 ms, filter time is increased back to 560 ms .
VIN undervoltage lockout	VIN_UVLO	Falling 3.9 V Rising 4 V	Yes	Yes	Detects undervoltage condition at VIN pin. Sensed in all operating modes. Fault is detected if undervoltage condition duration is 100 µs minimum.
Open LED fault	OPEN_LED	LOW_COMP threshold	Yes	No	Detected if the voltage of one or more current sinks is below threshold level, and DC-DC adaptive control has reached maximum voltage. Open string is removed from the DC-DC voltage control loop and current sink is disabled. Fault pin is released by toggling VDDIO/EN pin. If VDDIO/EN is low for a period of 2 µs to 20 µs, LEDs are turned off for this period but device stays ACTIVE. If VDDIO/EN is low longer, device goes to STANDBY and restarts when EN goes high again.
Shorted LED fault	SHORT_LED	Shorted string detection level 6 V	Yes	No	Detected if the voltage of one or more current sinks is above shorted string detection level and at least one OUTx voltage is within headroom window. Shorted string is removed from the DC-DC voltage control loop and current sink is disabled. Fault pin is released by toggling VDDIO/EN pin. If VDDIO/EN is low for a period of 220 µs, LEDs are turned off for this period but device stays ACTIVE. If VDDIO/EN is low longer, device goes to STANDBY and restarts when EN goes high again.
Thermal protection	TSD	165°C Thermal shutdown hysteresis 20°C	Yes	Yes	Thermal shutdown is monitored from the beginning of soft start. Die temperature must decrease by 20°C for device to recover.



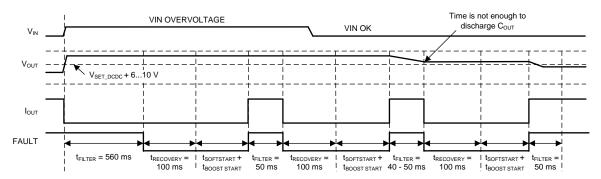


Figure 13. V_{IN} Overvoltage Protection (DC-DC OVP)

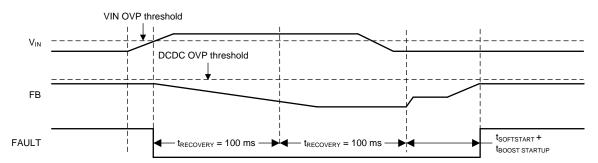


Figure 14. V_{IN} Overvoltage Protection (V_{IN} OVP)

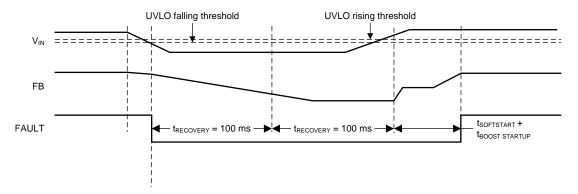


Figure 15. V_{IN} Undervoltage Lockout



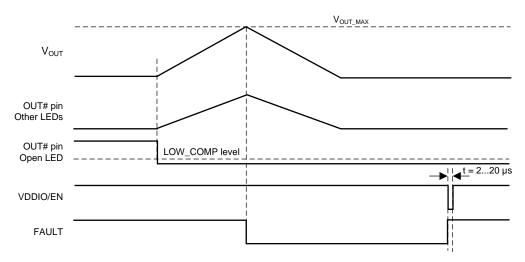


Figure 16. LED Open Fault

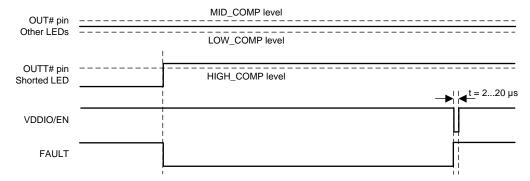


Figure 17. LED Short Fault

8.4 Device Functional Modes

8.4.1 Device States

The TPS61194-Q1 enters STANDBY mode when the internal LDO output rises above the power-on reset level, $V_{LDO} > V_{POR}$. In STANDBY mode the device is able to detect VDDIO/EN signal. When VDDIO/EN is pulled high, the device powers up. After start LED outputs are sensed to detect grounded outputs. Grounded outputs are disabled and excluded from the adaptive voltage control loop of the DC-DC.

If a fault condition is detected, the device enters FAULT_RECOVERY state. Faults that cause the device to enter FAULT_RECOVERY are listed in Table 3. When LED open or short is detected, the faulty string is disabled, but device stays in ACTIVE mode.



Device Functional Modes (continued)

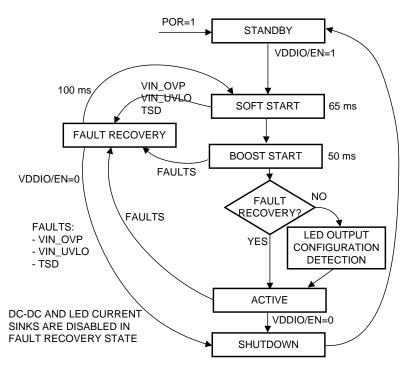


Figure 18. State Diagram

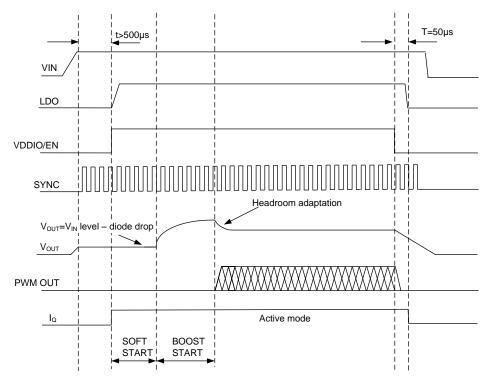


Figure 19. Timing Diagram for the Typical Start-Up and Shutdown



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The TPS61194-Q1 is designed for automotive applications, and an input voltage (V_{IN}), intended to be connected to the automotive battery, supports input voltage range from 4.5 V to 40 V. Device internal circuitry is powered from the integrated LDO.

The TPS61194-Q1 uses a simple four-wire control:

- VDDIO/EN for enable
- PWM input for brightness control
- SYNC pin for boost synchronisation (optional)
- · FAULT output to indicate fault condition (optional)

9.2 Typical Applications

9.2.1 Typical Application for 4 LED Strings

Figure 20 shows the typical application for TPS61194-Q1 which supports 4 LED strings, 80 mA per string, , with a boost switching frequency of 300 kHz.

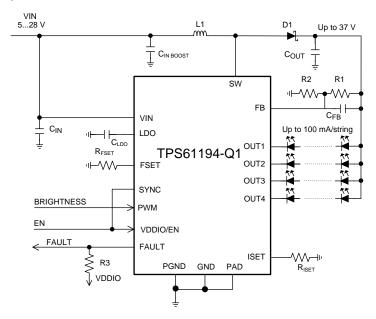


Figure 20. Four Strings 80 mA per String Configuration



Typical Applications (continued)

9.2.1.1 Design Requirements

DESIGN PARAMETER	VALUE
V _{IN} voltage range	4.5 V – 28 V
LED string	4P8S LEDs (30 V)
LED string current	100 mA
Maximum boost voltage	37 V
Boost switching frequency	300 kHz
External boost sync	not used
Boost spread spectrum	enabled
L1	33 μH
C _{IN}	100 μF, 50 V
C _{IN BOOST}	$2 \times (10$ - μ F, 50-V ceramic) + 33- μ F, 50-V electrolytic
C _{OUT}	$2 \times (10 - \mu F, 50 - V \text{ ceramic}) + 33 - \mu F, 50 - V \text{ electrolytic}$
C _{FB}	15 pF
C _{LDO}	1 μF, 10 V
R _{ISET}	24 kΩ
R _{FSET}	210 kΩ
R1	750 kΩ
R2	130 kΩ
R3	10 kΩ

9.2.1.2 Detailed Design Procedure

9.2.1.2.1 Inductor Selection

There are two main considerations when choosing an inductor; the inductor must not saturate, and the inductor current ripple must be small enough to achieve the desired output voltage ripple. Different saturation current rating specifications are followed by different manufacturers so attention must be given to details. Saturation current ratings are typically specified at 25°C. However, ratings at the maximum ambient temperature of application should be requested from the manufacturer. Shielded inductors radiate less noise and are preferred. The saturation current must be greater than the sum of the maximum load current, and the worst case averageto-peak inductor current. Equation 4 shows the worst case conditions

$$\begin{split} I_{SAT} &> \frac{I_{OUTMAX}}{D'} + I_{RIPPLE} \quad \text{For Boost} \\ \text{Where } I_{RIPPLE} &= \frac{(V_{OUT} - V_{IN})}{(2 \text{ x L x f})} \text{ x } \frac{V_{IN}}{V_{OUT}} \\ \text{Where } D &= \frac{(V_{OUT} - V_{IN})}{(V_{OUT})} \text{ and } D' = (1 - D) \end{split}$$

- IRIPPLE peak inductor current
- I_{OUTMAX} maximum load current
- V_{IN} minimum input voltage in application
- · L min inductor value including worst case tolerances
- f minimum switching frequency
- V_{OUT} output voltage

• D - Duty Cycle for CCM Operation

As a result, the inductor should be selected according to the I_{SAT}. A more conservative and recommended approach is to choose an inductor that has a saturation current rating greater than the maximum current limit. A saturation current rating of at least 2.5 A is recommended for most applications. See Table 2 for recommended inductance value for the different switching frequency ranges. The inductor's resistance should be less than 300 m Ω for good efficiency.



See detailed information in *Understanding Boost Power Stages in Switch Mode Power Supplies*. Power Stage Designer[™] Tool can be used for the boost calculation: http://www.ti.com/tool/powerstage-designer.

9.2.1.2.2 Output Capacitor Selection

A ceramic capacitor with $2 \times V_{MAX BOOST}$ or more voltage rating is recommended for the output capacitor. The DC-bias effect can reduce the effective capacitance by up to 80%, which needs to be considered in capacitance value selection. Capacitance recommendations for different switching frequencies are shown in Table 2. To minimize audible noise of ceramic capacitors their physical size should typically be minimized.

9.2.1.2.3 Input Capacitor Selection

A ceramic capacitor with $2 \times V_{\text{IN MAX}}$ or more voltage rating is recommended for the input capacitor. The DC-bias effect can reduce the effective capacitance by up to 80%, which needs to be considered in capacitance value selection. Capacitance recommendations for different boost switching frequencies are shown in Table 2.

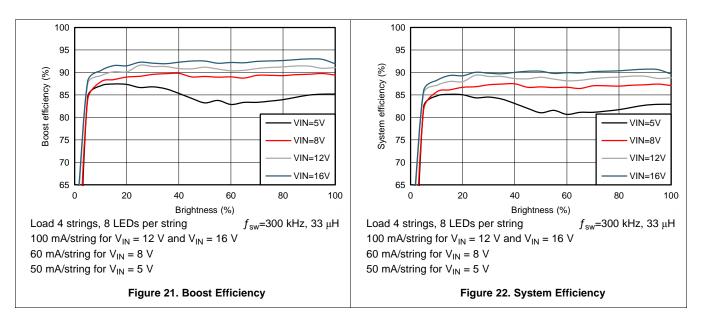
9.2.1.2.4 LDO Output Capacitor

A ceramic capacitor with at least 10-V voltage rating is recommended for the output capacitor of the LDO. The DC-bias effect can reduce the effective capacitance by up to 80%, which needs to be considered in capacitance value selection. Typically a $1-\mu F$ capacitor is sufficient.

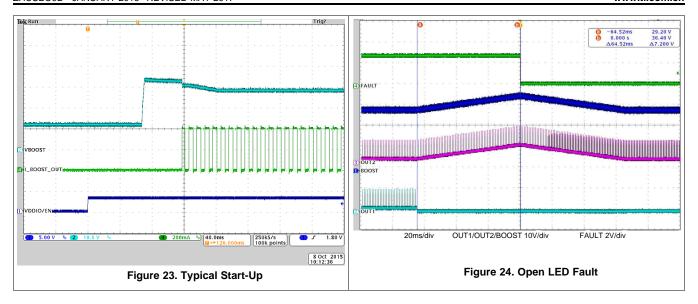
9.2.1.2.5 Diode

A Schottky diode should be used for the boost output diode. Do not use ordinary rectifier diodes because slow switching speeds and long recovery times degrade the efficiency and the load regulation. Diode rating for peak repetitive current should be greater than inductor peak current (up to 3 A) to ensure reliable operation in boost mode. Average current rating should be greater than the maximum output current. Schottky diodes with a low forward drop and fast switching speeds are ideal for increasing efficiency. Choose a reverse breakdown voltage of the Schottky diode significantly larger than the output voltage.

9.2.1.3 Application Curves







9.2.2 SEPIC Mode Application

When LED string voltage can be above or below V_{IN} voltage, SEPIC configuration can be used. In this example, two separate coils are used for SEPIC. This can enable lower height external components to be used, compared to a coupled coil solution. On the other hand, coupled coil typically maximizes the efficiency. Also, in this example, an external clock is used to synchronize SEPIC switching frequency. External clock input can be modulated to spread switching frequency spectrum.

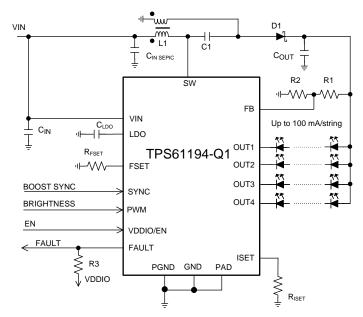


Figure 25. SEPIC Mode, 4 Strings, 100 mA per String Configuration



9.2.2.1 Design Requirements

DESIGN PARAMETER	VALUE
V _{IN} voltage range	4.5 V – 30 V
LED string	4P2S LEDs (7.2 V)
LED string current	100 mA
Maxmum output voltage	10 V
SEPIC switching frequency	2.2 MHz
External sync for SEPIC	used
Spread spectrum	Internal spread spectrum disabled (external sync used)
L1, L2	10 μH
C _{IN}	10 μF 50 V
C _{IN SEPIC}	2×10 - μ F, 50-V ceramic + 33 μ F 50-V electrolytic
C1	10-μF 50-V ceramic
C _{OUT}	2×10 - μ F, 50-V ceramic + 33 μ F 50-V electrolytic
C _{LDO}	1 μF, 10 V
R _{ISET}	24 kΩ
R _{FSET}	24 kΩ
R1	184 kΩ
R2	130 kΩ
R3	10 kΩ

9.2.2.2 Detailed Design Procedure

In SEPIC mode the maximum voltage at the SW pin is equal to the sum of the input voltage and the output voltage. Because of this, the maximum sum of input and output voltage must be limited below 50 V. See *Detailed Design Procedure* for general external component guidelines. Main differences of SEPIC compared to boost are described below.

Power Stage Designer™ Tool can be used for modeling SEPIC behavior: http://www.ti.com/tool/powerstage-designer. For detailed explanation on SEPIC see Texas Instruments Analog Applications Journal Designing DC/DC Converters Based on SEPIC Topology (SLYT309).

9.2.2.2.1 Inductor

In SEPIC mode, currents flowing through the coupled inductors or the two separate inductors L1 and L2 are the input current and output current, respectively. Values can be calculated using *Power Stage Designer™ Tool* or using equations in SLYT309.

9.2.2.2.2 Diode

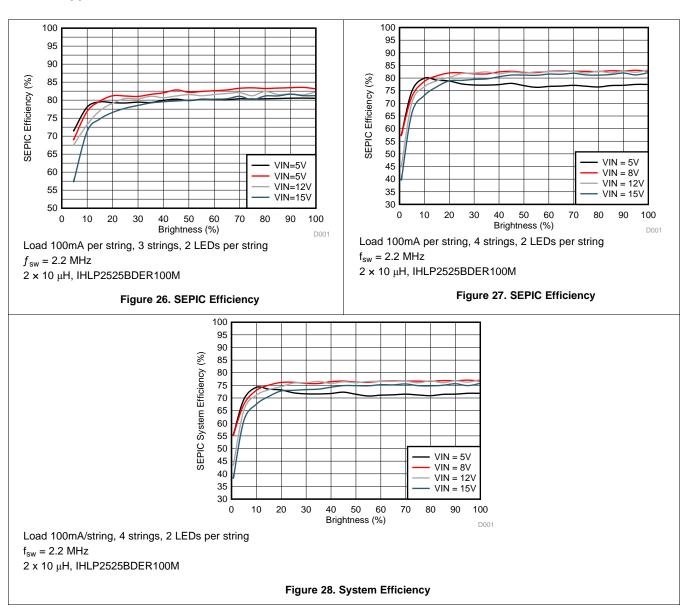
In SEPIC mode diode peak current is equal to the sum of input and output currents. Diode rating for peak repetitive current should be greater than SW pin current limit (up to 3 A for transients) to ensure reliable operation in boost mode. Average current rating should be greater than the maximum output current. Diode voltage rating must be higher than sum of input and output voltages.

9.2.2.2.3 Capacitor C1

Ti recommends a ceramic capacitor with low ESR. Diode voltage rating must be higher than maximum input voltage.

TEXAS INSTRUMENTS

9.2.2.3 Application Curves



10 Power Supply Recommendations

The device is designed to operate from an automotive battery. Device should be protected from reversal voltage and voltage dump over 50 V. The resistance of the input supply rail must be low enough so that the input current transient does not cause too high drop at TPS61194-Q1 VIN pin. If the input supply is connected by using long wires additional bulk capacitance may be required in addition to the ceramic bypass capacitors in the V_{IN} line.



11 Layout

11.1 Layout Guidelines

Figure 29 is a layout recommendation for TPS61194-Q1 used to demonstrate the principles of a good layout. This layout can be adapted to the actual application layout if or where possible. It is important that all boost components are close to the chip, and the high current traces must be wide enough. By placing boost components on one side of the chip it is easy to keep the ground plane intact below the high current paths. This way other chip pins can be routed more easily without splitting the ground plane. Bypass LDO capacitor must be placed as close as possible to the device.

Here are some main points to help the PCB layout work:

- Current loops need to be minimized:
 - For low frequency the minimal current loop can be achieved by placing the boost components as close as
 possible to the SW and PGND pins. Input and output capacitor grounds must be close to each other to
 minimize current loop size.
 - Minimal current loops for high frequencies can be achieved by making sure that the ground plane is intact under the current traces. High-frequency return currents find a route with minimum impedance, which is the route with minimum loop area, not necessarily the shortest path. Minimum loop area is formed when return current flows just under the *positive*current route in the ground plane, if the ground plane is intact under the route.
- The GND plane must be intact under the high current boost traces to provide shortest possible return path and smallest possible current loops for high frequencies.
- Current loops when the boost switch is conducting and not conducting must be on the same direction in optimal case.
- Inductors must be placed so that the current flows in the same direction as in the current loops. Rotating inductor 180° changes current direction.
- Use separate power and noise-free grounds. Power ground is used for boost converter return current and noise-free ground for more sensitive signals, such as LDO bypass capacitor grounding as well as grounding the GND pin of the device.
- Boost output feedback voltage to LEDs must be taken out after the output capacitors, not straight from the diode cathode.
- Place LDO 1-µF bypass capacitor as close as possible to the LDO pin.
- Input and output capacitors require strong grounding (wide traces, many vias to GND plane).
- If two output capacitors are used they must have symmetrical layout to get both capacitors working ideally.
- Output ceramic capacitors have a DC-bias effect. If the output capacitance is too low, it can cause boost to become unstable on some loads, and this increases EMI. DC-bias characteristics should be obtained from the component manufacturer; they are not taken into account on component tolerance. TI recommends X5R/X7R capacitors.



11.2 Layout Example

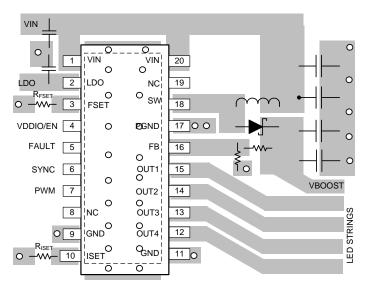


Figure 29. TPS61194-Q1 Boost Layout



12 器件和文档支持

12.1 器件支持

12.1.1 开发支持

Power Stage Designer™工具可用于升压和 SEPIC 模式: http://www.ti.com.cn/tool/cn/powerstage-designer

12.2 文档支持

12.2.1 相关文档

请参阅如下相关文档:

- 《PowerPAD™ 耐热增强型封装》
- 《了解开关模式电源中的升压功率级》
- 《基于 SEPIC 拓扑设计 DC/DC 转换器》

12.3 接收文档更新通知

要接收文档更新通知,请导航至德州仪器 Tl.com.cn 上的器件产品文件夹。请单击右上角的通知我进行注册,即可收到任意产品信息更改每周摘要。有关更改的详细信息,请查看任意已修订文档中包含的修订历史记录。

12.4 社区资源

下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商"按照原样"提供。这些内容并不构成 TI 技术规范,并且不一定反映 TI 的观点:请参阅 TI 的 《使用条款》。

TI E2E™ 在线社区 TI 的工程师对工程师 (E2E) 社区。此社区的创建目的在于促进工程师之间的协作。在 e2e.ti.com 中,您可以咨询问题、分享知识、拓展思路并与同行工程师一道帮助解决问题。

设计支持 71 参考设计支持 可帮助您快速查找有帮助的 E2E 论坛、设计支持工具以及技术支持的联系信息。

12.5 商标

Power Stage Designer, E2E are trademarks of Texas Instruments. All other trademarks are the property of their respective owners.

12.6 静电放电警告



这些装置包含有限的内置 ESD 保护。 存储或装卸时,应将导线一起截短或将装置放置于导电泡棉中,以防止 MOS 门极遭受静电损伤。

12.7 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 机械、封装和可订购信息

以下页面包括机械、封装和可订购信息。这些信息是指定器件的最新可用数据。这些数据发生变化时,我们可能不会另行通知或修订此文档。如欲获取此产品说明书的浏览器版本,请参阅左侧的导航栏。



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS61194PWPRQ1	ACTIVE	HTSSOP	PWP	20	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	61194Q	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PWP (R-PDSO-G20) PowerPAD™ SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPADTM package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

Exposed Thermal Pad Dimensions

4206332-15/AO 01/16

NOTE: A. All linear dimensions are in millimeters

<u>/A</u> Exposed tie strap features may not be present.

PowerPAD is a trademark of Texas Instruments



PWP (R-PDSO-G20)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



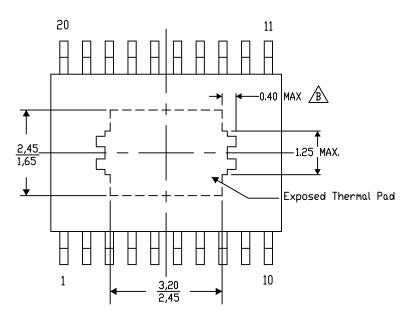
PWP (R-PDSO-G20) PowerPAD™ SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPADTM package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

Exposed Thermal Pad Dimensions

4206332-18/AO 01/16

NOTE: A. All linear dimensions are in millimeters

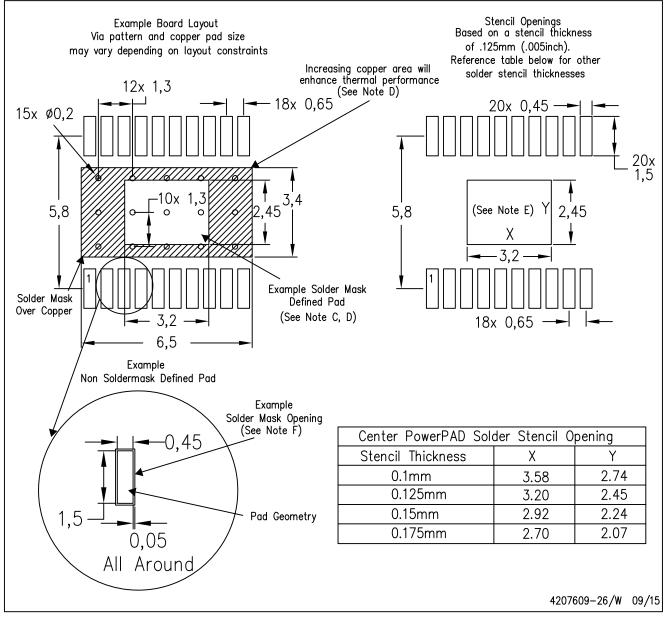
🛕 Exposed tie strap features may not be present.

PowerPAD is a trademark of Texas Instruments



PWP (R-PDSO-G20)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



重要声明和免责声明

TI"按原样"提供技术和可靠性数据(包括数据表)、设计资源(包括参考设计)、应用或其他设计建议、网络工具、安全信息和其他资源,不保证没有瑕疵且不做出任何明示或暗示的担保,包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任:(1) 针对您的应用选择合适的 TI 产品,(2) 设计、验证并测试您的应用,(3) 确保您的应用满足相应标准以及任何其他功能安全、信息安全、监管或其他要求。

这些资源如有变更,恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的应用。严禁对这些资源进行其他复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务,TI 对此概不负责。

TI 提供的产品受 TI 的销售条款或 ti.com 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

邮寄地址:Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2022,德州仪器 (TI) 公司